

10/799380

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

Applicant: Meikei Ieong, et al.

**Docket: 16963Z** 

Patent No: 7,023,057

**Dated: August 09, 2006** 

**Issued: April 04, 2006** 

For: CMOS ON HYBRID SUBSTRATE WITH DIFFERENT

CRYSTAL ORIENTATIONS USING SILICON-TO-SILICON

**DIRECT WAFER BONDING** 

**Commissioner of Patents** P.O. Box 1450 Alexandria, VA 22313-1450

## REQUEST FOR CERTIFICATE OF CORRECTION

Sir:

It appearing that errors have been introduced in the course of printing the Patent issued in the above application, it is respectfully requested that the Commissioner issue a Certificate of Correction in the following respects:

Column 4, Line 45: "NFET" should read - nFET -

Column 12, Line 22: "FIG. 1" should read - FIG. 11 - Certificate

AUG 1 5 2006

of Correction

Respectfully submitted,

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AUR 15 2006

## UNITED STATES PATENT AND TRADEMARK OFFICE **CERTIFICATE OF CORRECTION**

PATENT NO

: 7,023,057

**APPLICATION NO: 10/799,380** 

ISSUE DATE

: April 04, 2006

INVENTOR(S)

: Meikei leong, et al.

It is certified that an error appears or errors appear in the above-identified patent and that said Letters Patent is hereby corrected as shown below:

Column 4, Line 45:

"NFET" should read -- nFET --

Column 12, Line 22:

"FIG. 1" should read -- FIG. 11 --

MAILING ADDRESS OF SENDER:

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PATENT No. 7,023,057

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